

<b>Notice of References Cited</b>	Application/Control No. 09/651,790	Applicant(s)/Patent Under Reexamination BALUSWAMY ET AL.	
	Examiner Marcos D. Pizarro-Crespo	Art Unit 2814	Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-5,883,012	03-1999	Chiou et al.	438/748
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

**FOREIGN PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Ghandhi, VLSI Fabrication Principles Silicon and Gallium Arsenide, 2nd ed., 1994, John Wiley & Sons, Inc., New York, pp.589
	V	
	W	
	X	

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
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